Localization of transverse waves in randomly layered media at oblique incidence

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(Received 2 July 2004; published 27 December 2004)

We investigate the oblique incidence of electromagnetic waves on a randomly layered medium in the limit of strong disorder. An approximate method for calculating the inverse localization length based on the assumptions of zero-energy flux and complete phase stochastization is presented. Two effects not found at normal incidence have been studied: dependence of the localization length on the polarization and decrease of the localization length due to the internal reflections from layers with small refractive indexes. The inverse localization length (attenuation rate) for P-polarized radiation is shown to be always smaller than that of S waves, which is to say that long enough randomly layered sample polarizes transmitted radiation. The localization length for P polarization depends nonmonotonically on the angle of propagation and under certain conditions turns to infinity at some angle, which means that typical (nonresonant) random realizations become transparent at this angle of incidence (stochastic Brewster effect).

DOI: 10.1103/PhysRevB.70.245121 PACS number(s): 42.25.Dd, 41.20.Jb, 42.25.Ja, 72.15.Rn

I. INTRODUCTION

Localization of classical waves and quantum particles in one-dimensional (1D) disordered systems is well studied theoretically (see, for example, Refs. 1 and 2 and references therein). An important application of the theory is the propagation of radiation in randomly layered media where the refractive index depends on a single coordinate. In general, however, this is a three-dimensional problem, which is reduced to a 1D one only when the direction of propagation is normal to the layers. In this case the field $\psi(z)$ of a monochromatic wave obeys a Schrödinger-type equation with energy-dependent effective potential

$$-\frac{d^2\psi(z)}{dz^2} + k^2 \delta \varepsilon(z)\psi(z) = k^2 \psi(z), \tag{1}$$

where the z axis is normal to the layers, $k = \sqrt{\varepsilon_0}\omega/c$, ω is the frequency, $\delta\varepsilon(z) = -\Delta\varepsilon(z)/\varepsilon_0$, and the dielectric constant of the medium is given by

$$\varepsilon(z) = \varepsilon_0 + \Delta \varepsilon(z), \tag{2}$$

with $\Delta \varepsilon(z)$ being a random function of the coordinate. The important distinction of Eq. (1) from the corresponding quantum-mechanical equation for electrons is that the "energy" k^2 in Eq. (1) is always higher than the "potential" $k^2 \delta \varepsilon$ (unless $\Delta \varepsilon/\varepsilon_0 < -1$); i.e., only "above-barrier" scattering takes place. In other words, total internal reflection never occurs at normal incidence and localization in this case is due to the interference of the multiply scattered random fields.

The situation is, however, different when oblique (with respect to z axis) incidence is considered. In this instance the field can be presented as $\psi(\mathbf{r}) = \exp(ik_x x + ik_y y)\chi(z)$ (k_x and k_y are x and y components of the wave vector, respectively) and the equation for the z-dependent term $\chi(z)$ takes the form

$$-\frac{d^2\chi(z)}{dz^2} + k^2 \delta \varepsilon(z) \chi(z) = (k^2 - k_x^2 - k_y^2) \chi(z).$$
 (3)

Obviously the "energy" $k^2 - k_x^2 - k_y^2$ may take any positive value, in particular can be less than the "potential" $k^2 \delta \varepsilon$. It gives rise to an additional mechanism of localization, which is due to the internal reflection and tunneling.

Another new effect, which is absent in pure 1D random systems, comes about at oblique propagation of transverse vector waves. In this case the symmetry with respect to the direction of propagation is broken, and the localization length depends significantly on the polarization of the radiation. This phenomenon is a consequence of the dependence of Fresnel reflection and transmission coefficients on the wave polarization.³

In this paper we present an approximate method for calculating the localization length in a randomly layered medium based on the assumptions of the exponentially small transmission and complete phase randomization (Sec. II). In Sec. III we use this method to calculate the localization length for two orthogonal linear polarizations. It is shown that the localization length of the wave with the vector of the electric field orthogonal to the plane of incidence (S wave) is always larger than that of P waves (with the electric vector in the plane of incidence), for which a sort of stochastic Brewster effect takes place. As the result, the radiation transmitted through a long enough randomly layered sample is always P polarized (with an exponential accuracy). The effect on the localization length of the internal reflection at the interfaces between random layers is studied in Sec. IV. Some examples of randomly layered media have been considered.

II. METHOD OF CALCULATION OF THE LOCALIZATION LENGTH IN A RANDOMLY LAYERED MEDIUM

It is well known that the modulus of the reflection coefficient R of a plane monochromatic wave incident on a ran-

domly layered half-space is equal to 1 and there is no energy flux inside the medium generated by the incident wave. 1,2,4 When a randomly layered sample has a finite but large enough length L, then |R(L)| differs from unity by an exponentially small number $1-|R(L)|^2 \propto \exp(-2L/l_{\rm loc})$ ($L \gg l_{\rm loc}$, is the localization length), and the flux along the system is exponentially small, $\propto \exp(-2L/l_{\rm loc})$. This *a priori* information enables one to assume that if a plane wave with frequency ω is incident normally (along z axis) on a sample from left, the field in each jth layer inside the sample can be considered (with an exponential accuracy) a standing wave and presented as

$$\psi_i = A_i \exp(i\omega t) \cos[k_i(z - z_i) + \varphi_i]. \tag{4}$$

Here A_j is the real amplitude, $k_j = n_j \omega/c$, n_j is the refractive index, and φ_j is the (real) phase at the layer's right-hand boundary located at a point z_j . Such a presentation of the phase is dictated by the fact that the transmission problem for the wave incident from the left can be formulated as an evolutional one with initial conditions given at the right edge of the sample.^{4,5}

Thus the wave propagation problem is reduced to the oscillatory one with a single unknown real amplitude and real phase, Eq. (4). This simplifies the problem significantly as compared to the conventional transfer matrix method,^{6–9} where the evolution of two independent waves in each layer is considered. To calculate the localization length we use the standard definition¹

$$I_{\text{loc}}^{-1} = -\left\langle \frac{\ln T}{2L} \right\rangle = -\lim_{L \to \infty} \left(\frac{\ln T}{2L} \right),\tag{5}$$

where T is the transmission coefficient of a random sample. Notice that the inverse localization length $l_{\rm loc}^{-1}$ is a self-averaging quantity, which means that the value measured at any finite but long enough realization coincides with the exponential accuracy with its mean value.

We represent $\ln T$ as

$$\ln T = \ln \left(\frac{A_{N+1}}{A_0}\right)^2 = 2 \ln \left(\frac{A_{N+1}}{A_N} \frac{A_N}{A_{N-1}} \cdots \frac{A_1}{A_0}\right) = 2 \sum_{j=0}^{N} \ln \frac{A_{j+1}}{A_j},$$
(6)

where N is the total number of layers, A_0 and A_{N+1} are field amplitudes to the left and to the right of the sample correspondingly. By substituting Eq. (6) into Eq. (5) we obtain

$$I_{\text{loc}}^{-1} = -\lim_{N \to \infty} \left(L^{-1} \sum_{j=0}^{N} \ln \frac{A_{j+1}}{A_{j}} \right). \tag{7}$$

Note that $\lim_{N\to\infty} L/N = \langle s_j \rangle \equiv s$, where s_j is the thickness of the *j*th layer and s is the mean thickness of the layers. Since

$$\lim_{N\to\infty} \left[N^{-1} \sum_{j=0}^{N} \ln(A_{j+1}/A_j) \right] = \langle \ln(A_{j+1}/A_j) \rangle,$$

Eq. (7) becomes

$$I_{\text{loc}}^{-1} = s^{-1} \left\langle \ln \frac{A_j}{A_{j+1}} \right\rangle. \tag{8}$$

Thus the inverse localization length $l_{\rm loc}^{-1}$ is approximately equal to the inverse average thickness of layers times the mean logarithm of the ratio of field amplitudes in adjacent layers. The connection between (A_j, φ_j) and (A_{j+1}, φ_{j+1}) should be found from the boundary conditions at the corresponding interfaces and can be written in the most general form as

$$A_{j} = A_{j+1} f(\varphi_{j+1} - \Delta_{j+1}, \mu_{j}, \mu_{j+1}),$$

$$\varphi_{j} = g(\varphi_{j+1} - \Delta_{j+1}, \mu_{j}, \mu_{j+1}).$$
(9)

Here f and g are some real functions that determine properly the form of boundary conditions (see the examples in Secs. III and IV below), $\Delta_j = k_j s_j$ is the phase increment in the jth layer, and μ_j is a set of parameters, describing the random system (refractive index, impedance, density, etc.). The first equation in Eqs. (9) shows the linear connection of the amplitudes due to the linearity of the problem. The second one accounts for the phase change at the interface between two neighboring layers [see Eq. (4) and the paragraph below]. From Eqs. (9) and (8) it follows that

$$I_{\text{loc}}^{-1} = s^{-1} \langle \ln f(\varphi_{j+1} - \Delta_{j+1}; \mu_j, \mu_{j+1}) \rangle, \tag{10}$$

where $\langle \cdots \rangle$ stands for the averaging over all random parameters $(s_j \text{ and } \mu_j)$ the function f depends on. The explicit form of the distribution of phases φ_j should be found from boundary conditions (9), which is rather formidable task in the general case. The problem, however, is simplified significantly in the high-frequency limit, when the disorder is strong enough that the phases $(\varphi_j - \Delta_j)$ can be considered as independent random variables homogeneously distributed in the interval $(0,2\pi)$. ^{1,4,6–11} In this instance Eq. (10) takes the form

$$l_{\text{loc}}^{-1} = s^{-1} \int \int d\mu' d\mu'' P(\mu') P(\mu'')$$

$$\times \frac{1}{2\pi} \int_{0}^{2\pi} d\varphi' \ln f(\varphi', \mu'', \mu'),$$
(11)

where $P(\mu)d\mu$ is the joint probability density distribution of parameters μ . Equation (11) enables calculation of the inverse localization constant in the high-frequency limit for linear waves of any nature (electromagnetic, acoustic, or seismic, etc.). The method is rather general and can be easily modified for different kinds of random systems, for instance, periodical in some parameter(s) or those containing several types of layers with different dielectric properties and statistics. Examples of such systems are considered in Secs. III and IV.

III. POLARIZATION DEPENDENCE

In this section we study the oblique propagation of electromagnetic waves in a passive dielectric medium, which consists of an alternating sequence of layers with random thicknesses s_j and random real dielectric constants ε_j . The electric **E** and magnetic **H** fields of the wave are described by Maxwell equations

curl
$$\mathbf{E} - ik_0 \mathbf{H} = 0$$
,
curl $\mathbf{H} + ik_0 \varepsilon(z) \mathbf{E} = 0$, (12)

where $k_0 \equiv \omega/c$ and $\varepsilon(z)$ is the generalized telegraphic random process. Without loss of generality we assume that k_y =0 and consider two mutually orthogonal waves with H_y = E_x = E_z =0, E_y =E(z) and E_y = H_x = H_z =0, H_y =H(z) (S and P waves, respectively). These waves are the independent eigenmodes of the one-dimensionally inhomogeneous medium that propagate without interaction and change of polarization [this follows immediately from Eqs. (14) and (15) below]. After the substitution

$$\mathbf{E} \to \mathbf{E}(z) \exp(ik_x x),$$

$$\mathbf{H} \to \mathbf{H}(z) \exp(ik_x x), \tag{13}$$

the system of equations (12) can be reduced to two independent equations for nonzero components of P and S waves:

$$\frac{d^2E}{dz^2} + k_z^2 E = 0, (14)$$

$$\frac{d^2H}{dz^2} - \frac{1}{\varepsilon} \frac{d\varepsilon}{dz} \frac{dH}{dz} + k_z^2 H = 0.$$
 (15)

Here

$$k_z(z) = \sqrt{k_0^2 n^2(z) - k_x^2} = k_0 \sqrt{n^2(z) - n_c^2},$$
 (16)

where $n(z) = \sqrt{\varepsilon(z)}$ is the (random) refractive index and $n_c = k_x/k_0 = \sin \vartheta_0$ is its critical value (ϑ_0 is the angle between the wave vector in vacuum and z axis). A layer is transparent when $n > n_c$ and reflecting when $n < n_c$ (actually, in any case, a finite layer has finite nonzero transmittance; however, at $n < n_c$, there are only evanescent modes exist in the layer).

To calculate the inverse localization length for S waves, $l_{\log_S}^{-1}$, we use the general result of Sec. II: namely, Eq. (11), where the explicit expression for the function f should be substituted. In accordance with Eq. (4), the electric field E of the S wave in the jth layer [solution of Eq. (14)] can be written as

$$E_j = A_j \cos[k_{z_i}(z - z_j) + \varphi_j].$$
 (17)

Then, from the continuity conditions for the tangential component of the electric field and its normal derivative $dE_y/dz \sim H_x$ at the interface between the *j*th and (j+1)th layers it follows that

$$A_{j}\cos\varphi_{j} = A_{j+1}\cos(\varphi_{j+1} - \Delta_{j+1}),$$

$$A_{j}k_{z_{j}}\sin\varphi_{j} = A_{j+1}k_{z_{j+1}}\sin(\varphi_{j+1} - \Delta_{j+1}).$$
(18)

From Eq. (18) we derive

$$A_{j} = A_{j+1} f_{S}(\varphi_{j+1} - \Delta_{j+1}, n_{j}, n_{j+1}),$$

$$f_{S} = \left[\cos^{2}(\varphi_{j+1} - \Delta_{j+1}) + \frac{k_{z_{j+1}}^{2}}{k_{z_{j}}^{2}} \sin^{2}(\varphi_{j+1} - \Delta_{j+1})\right]^{1/2}$$
(19)

[see Eq. (9)]. Phase averaging—i.e., integration over the variable φ in Eq. (11) with f given by Eq. (19)—can be performed taking into account that

$$\frac{1}{2\pi} \int_{0}^{2\pi} \ln(a^2 \sin^2 \varphi + b^2 \cos^2 \varphi) d\varphi = \ln \frac{(a+b)^2}{4}.$$

This gives

$$l_{\text{loc}_{S}}^{-1} = s^{-1} \int_{n' > n_{c}} dn' F_{n}(n')$$

$$\times \int_{n'' > n_{c}} dn'' F_{n}(n'') \ln \left\{ \frac{1}{2} \left[1 + \frac{k_{z}(n')}{k_{z}(n'')} \right] \right\}. \quad (20)$$

Here $k_z(n)$ is given by Eq. (16), and F_n is the distribution function of the refractive indices n_j of the layers. The limits of integration in Eq. (20) follow from the simplifying assumption that all layers are transparent. The effect of reflecting layers is considered in Sec. IV.

Inverse localization length for P waves, $I_{loc_p}^{-1}$, can be calculated in the same way, by using the continuity conditions for the tangential component of the magnetic field H [Eq. (15)] and for $\varepsilon^{-1}dH_y/dz \sim E_x$. It is easy to show that in this instance

$$A_{j} = A_{j+1} f_{P}(\varphi_{j+1} - \Delta_{j+1}, n_{j}, n_{j+1}),$$

$$f_{P} = \left[\cos^{2}(\varphi_{j+1} - \Delta_{j+1}) + \frac{k_{z_{j+1}}^{2} n_{j}}{k_{z_{j}}^{2} n_{j+1}} \sin^{2}(\varphi_{j+1} - \Delta_{j+1}) \right]^{1/2}.$$
(21)

Note that the expression for f_P , Eq. (21), coincides with that for f_S , Eq. (23), after substitution $k_{z_j} \rightarrow k_{z_j}/n_j^2$. Therefore, the same substitution in Eq. (20) yields

$$I_{loc_{p}}^{-1} = s^{-1} \int_{n' > n_{c}} dn' F_{n}(n')$$

$$\times \int_{n'' > n_{c}} dn'' F_{n}(n'') \ln \left\{ \frac{1}{2} \left[1 + \frac{n''^{2} k_{z}(n')}{n'^{2} k_{z}(n'')} \right] \right\}. \quad (22)$$

Equations (20) and (22) show that the localization lengths of S and P waves are different. To compare them it is convenient to rewrite expressions (20) and (22) in the symmetrical with respect to the integration variables n' and n'' in the form

$$I_{\text{loc}_{S}}^{-1} = (2s)^{-1} \int_{n' > n_{c}} dn' F_{n}(n') \int_{n'' > n_{c}} dn'' F_{n}(n'') \ln A(n', n''),$$

$$A = \frac{\left[k_{z}(n') + k_{z}(n'')\right]^{2}}{4k_{z}(n')k_{z}(n'')},$$
(23)

$$l_{\text{loc}_{p}}^{-1} = (2s)^{-1} \int_{n' > n_{c}} dn' F_{n}(n') \int_{n'' > n_{c}} dn'' F_{n}(n'') \ln B(n', n''),$$

$$B = \frac{\left[n''^{2} k_{z}(n') + n'^{2} k_{z}(n'')\right]^{2}}{4n'^{2} n''^{2} k_{z}(n') k_{z}(n'')}.$$
(24)

It is easy to show that

$$d = A - B = \frac{(n'^2 - n''^2)^2 \sin^2 \vartheta_0}{4n'^2 n''^2 k_z(n') k_z(n'')} \ge 0,$$
 (25)

which means that

$$l_{\log_{\varsigma}}^{-1} \ge l_{\log_{p}}^{-1}.$$
 (26)

The equality in Eq. (26) corresponds to the "degenerate" cases of normal incidence, $\vartheta_0=0$, or to a homogeneous medium, $F_n(\zeta)=\delta(\zeta-n)$.

Thus the S wave is always stronger localized than the P wave. From Eqs. (23) and (24) it also follows that the transmission coefficients are different for different polarizations $T_{S,P} = \exp(-2L/l_{\log_{S,P}})$. It means that randomly layered medium acts as a *polarizer* for an obliquely propagating radiation. Indeed, if an incident wave has a mixed polarization, but the thickness of the randomly layered slab is large enough, the transmitted wave will be (with exponential accuracy) P polarized.

The difference in localization lengths grows with the increase of the angle of incidence. For example, at small angles of propagation, $\vartheta_0 \ll 1$, $\sin \vartheta_0 = n_c \ll n_j$, it can be readily shown from Eqs. (23) and (24) that

$$I_{\text{loc}_{S,P}}^{-1} = I_{\text{loc}_{0}}^{-1} \pm a \vartheta_{0}^{2} + O(\vartheta_{0}^{4}),$$

$$a = (2s)^{-1} \int dn' F_{n}(n') \int dn'' F_{n}(n'') \frac{(n' - n'')^{2}}{2n'^{2}n''^{2}},$$
(27)

where $l_{\text{loc}_0}^{-1}$ is the inverse localization length at normal propagation $(k_x = \sin \vartheta_0 = 0, k_z = k = k_0 n)$. One can see that when ϑ_0 increases, $l_{\text{loc}_y}^{-1}$ grows and $l_{\text{loc}_p}^{-1}$ decreases proportionally to ϑ_0^2 and symmetrically with respect to $l_{\text{loc}_0}^{-1}$. Obviously, the following inequality holds:

$$l_{\text{loc}_{S}}^{-1} > l_{\text{loc}_{0}}^{-1} > l_{\text{loc}_{P}}^{-1}.$$
 (28)

The rise of the localization length (weakening of localization) of the P wave with ϑ_0 increasing stems from the decrease of the reflection coefficient from the interface between two homogeneous media. If the media are infinite, the reflection coefficient for the P wave becomes zero at $\vartheta_0 = \vartheta_B$, where ϑ_B is the so-called Brewster angle. In general, in the case of a randomly layered medium the reflection coefficient does not turn to zero; however, the inverse localization length $I_{\log_P}^{-1}$ reaches a minimum at some angle $\vartheta_0 = \widetilde{\vartheta}_B$ that can be found from the condition

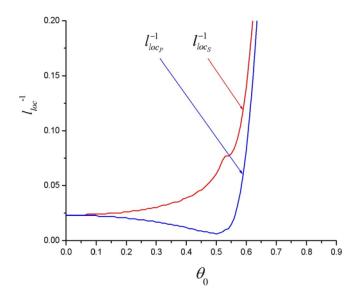


FIG. 1. (Color online) Dependences $l_{\log_P}^{-1}$ and $l_{\log_P}^{-1}$ on the angle of incidence, ϑ_0 . The curves are obtained by numerical calculations of Eqs. (41), (20), and (21) with rectangle distribution function (42) and the following values of the parameters: $n_{\min} = 0.5$, $n_{\max} = 1.5$, s = 1, and $k_0 = 100$. At $\vartheta_0 = \widetilde{\vartheta}_B \approx 0.5$ function $l_{\log_P}^{-1}(\vartheta_0)$ has a minimum; the angle $\widetilde{\vartheta}_B$ is an analog of the Brewster angle. At $\vartheta_0 > \arcsin n_{\min} \approx 0.52$ both functions rapidly increase because of the influence of reflected layers, which increase in number with ϑ_0 increasing.

$$\left. \frac{dl_{\text{loc}_p}^{-1}}{d\vartheta_0} \right|_{\vartheta_0 = \tilde{\vartheta}_p} = 0. \tag{29}$$

The dependence $l_{\log_{S,P}}^{-1}(\vartheta_0)$ for the case of rectangle distribution function F(n) (see Sec. IV) is shown in Fig. 1.

Interestingly, in the particular case of a layered medium built of alternating layers of two dielectrics with refractive indices n_1 and n_2 and random thicknesses, there exists a Brewster angle $\vartheta_0 = \vartheta_B$ at which the reflection coefficient of the P wave turns to zero and localization is absent: $l_{\text{loc}_P}^{-1} = 0$. In this case the inverse localization lengths can be calculated explicitly. To do this, boundary conditions (18) and (19) should be applied twice: for the transition from a layer n_1 to the adjacent layer n_2 and from the layer n_2 to the next layer n_1 . A similar problem for normal propagation was solved in Refs. 6–11. By multiplying together two equations like Eq. (19) we find

$$A_{j-1} = A_{j+1} \tilde{f}_{S}(\varphi_{j+1} - \Delta_{j+1}, \varphi_{j} - \Delta_{j}, n_{1}, n_{2}),$$

$$\tilde{f}_{S} = \left[\cos^{2}(\varphi_{j+1} - \Delta_{j+1}) + \frac{k_{z_{1}}^{2}}{k_{z_{2}}^{2}} \sin^{2}(\varphi_{j+1} - \Delta_{j+1}) \right]$$

$$\times \left[\cos^{2}(\varphi_{j} - \Delta_{j}) + \frac{k_{z_{2}}^{2}}{k_{z_{1}}^{2}} \sin^{2}(\varphi_{j} - \Delta_{j}) \right], \quad (30)$$

where $k_{z_{1,2}}^2 = k_0^2 n_{1,2}^2 - k_x^2$. After substituting Eq. (30) into an

equation similar to Eq. (11) and averaging over the phases $\varphi_{i+1} - \Delta_{i+1}$ and $\varphi_i - \Delta_i$, we obtain

$$I_{\text{loc}_S}^{-1} = \frac{1}{s_0} \ln \frac{(k_{z_1} + k_{z_2})^2}{4k_{z_1}k_{z_2}},$$
 (31)

$$l_{\text{loc}_p}^{-1} = \frac{1}{s_0} \ln \frac{(k_{z_1} n_2^2 + k_{z_2} n_1^2)^2}{4k_{z_1} k_{z_2} n_1^2 n_2^2}.$$
 (32)

Here $s_0 = s_1 + s_2$ is the mean thickness of the pair of the layers, and $s_{1,2}$ are the mean thicknesses of the layers with refractive indices $n_{1,2}$, respectively. If $k_{z1}n_2^2 = k_{z2}n_1^2$, the inverse localization length of the P wave, Eq. (32) turns to zero. This determines the Brewster angle for the considered layered medium:

$$\vartheta_B = \frac{n_1 n_2}{\sqrt{n_1^2 + n_2^2}}. (33)$$

If $\vartheta_0 = \vartheta_B$, localization is absent for the *P* wave. This circumstance is related to the fact that quantity k_z/n^2 plays role of the effective longitudinal wave number of the *P* wave. Then, if $k_z/n_1^2 = k_z/n_2^2$, the medium is effectively homogeneous.

IV. EFFECT OF THE INTERNAL REFLECTION

In Sec. II the localization length have been calculated under the assumption that the refractive index of all random layers was larger than a critical value $n_i > n_c = k_x/k_0 = \sin \vartheta_0$. This guaranteed that the angle of incidence at any interface between the jth and (j+1)th layers was always smaller than the angle of the total internal reflection, $\vartheta_i^{(\text{tot})}$, which corresponded to the above-barrier reflection of a quantum particle. In the general case, however, this restriction must be removed; i.e., for some layers inside the random system the inverse inequality $n_i < n_c$ may take place. It means that for these layers the local angle of incidence exceeds $\vartheta_{\cdot}^{(\text{tot})}$, and strong internal reflection from them should be taken into account. In what follows we call such layers "reflecting" to distinguish them from the "transparent" (with no internal reflection) ones. The longitudinal wave number k_z , Eq. (16), inside the jth reflecting layer is an imaginary number; therefore, the wave exponentially decays along the z axis. Nevertheless, the transmission coefficient is finite, and a wave with a finite amplitude is incident on the (j+1)th layer (we assume that $n_{j+1} > n_c$). Note that even a small amount of reflecting layers can contribute significantly to the inverse localization length-i.e., reduce dramatically the total transmission at typical realizations.

In calculating the inverse localization length for the S wave we follow the general procedure presented in Sec. II and start from Eq. (7). Since both transparent (tr) and reflecting (ref) layers are present, it is advantageous to separate the sum in Eq. (7) into two, each of them related to a particular type of layers. In doing this it is worthwhile to couple each reflecting layer with its left-hand-side transparent neighbor. The number of such pairs is equal to the number of reflecting slabs, $N_{\rm ref}$, while the amount of the remaining (uncoupled)

transparent slabs is $N_{\rm tr} - N_{\rm ref}$ ($N_{\rm tr}$ is the number of transparent layers). Taking this into account we can rewrite Eq. (7) as

$$I_{\text{loc}}^{-1} = -\lim_{N \to \infty} L^{-1} \left(\sum_{j=1}^{N_{\text{tr}} - N_{\text{ref}}} \ln \frac{A_{j+1}}{A_j} + \sum_{j=1}^{2N_{\text{ref}}} \ln \frac{A_{j+1}}{A_{j-1}} \right). \quad (34)$$

Under the assumption that the mean thicknesses of reflected and transparent layers are the same, s, the expression, Eq. (8), for the inverse localization length takes the form

$$I_{\text{loc}}^{-1} = -\left(\frac{N_{\text{tr}} - N_{\text{ref}}}{Ns} \left\langle \ln \frac{A_{j+1}}{A_{j}} \right\rangle_{\text{tr}} + \frac{N_{\text{ref}}}{Ns} \left\langle \ln \frac{A_{j+1}}{A_{j-1}} \right\rangle_{\text{ref}} \right)$$

$$\equiv \frac{N_{\text{tr}} - N_{\text{ref}}}{N} I_{\text{loc}_{\text{tr}}}^{-1} + \frac{2N_{\text{ref}}}{N} I_{\text{loc}_{\text{ref}}}^{-1}. \tag{35}$$

Here $l_{\text{loc}_{\text{tr}}}^{-1}$ stands for the inverse localization length in the medium that consists of transparent layers only, while

$$l_{\text{loc}_{\text{ref}}}^{-1} = (2s)^{-1} \left\langle \ln \frac{A_{j-1}}{A_{j+1}} \right\rangle_{\text{ref}}$$
 (36)

denotes the inverse localization length in the medium built of alternating transparent and reflected layers. Given the distribution function of the refractive index, $F_n(n)$, the numbers of layers can be calculated as

$$N_{\text{tr}} = N \int_{n' > n_c} F_n(n') dn', \quad N_{\text{ref}} = N \int_{n' < n_c} F_n(n') dn'.$$
 (37)

When $N_{\text{ref}}=0$ or $l_{\text{loc}_{\text{ref}}}^{-1}=l_{\text{loc}_{\text{tr}}}^{-1}$, Eq. (35) turns, as it must, into Eq. (8).

To find the ratios of the amplitudes involved in Eq. (35) we note that the electric field E_j inside the *j*th reflected layer is a superposition of two nonpropagating modes:

$$E_i = A_i \exp(-\gamma_i z) + B_i \exp(\gamma_i z), \tag{38}$$

with

$$\gamma_i = -ik_{z.} = \sqrt{k_x^2 - n_i^2 k_0^2} = k_0 \sqrt{n_c^2 - n_i^2}.$$
 (39)

The electric field in the adjacent (j-1)th and (j+1)th transparent layers is given by Eq. (17). The explicit form of general connections (9) follows from the conditions of continuity of the fields and their derivatives at the boundaries:

$$A_{j-1}\cos\varphi_{j-1} = A_j + B_j \exp(-\gamma_j s_j),$$

$$k_{z_{j-1}}A_{j-1}\sin\varphi_{j-1} = \gamma_j A_j - \gamma_j B_j \exp(-\gamma_j s_j),$$

$$A_j \exp(-\gamma_j s_j) + B_j = A_{j+1}\cos(\varphi_{j+1} - \Delta_{j+1}),$$

$$\gamma_j A_j \exp(-\gamma_j s_j) - \gamma_j B_j = k_{z_{j+1}}A_{j+1}\sin(\varphi_{j+1} - \Delta_{j+1}).$$
(40)

From Eqs. (40) one can derive

$$\begin{split} \frac{A_{j-1}^{2}}{A_{j+1}^{2}} &= \frac{1}{4\Gamma_{j}^{2}} \left(\cos \widetilde{\varphi}_{j+1} - \frac{k_{z_{j+1}}}{\gamma_{j}} \sin \widetilde{\varphi}_{j+1}\right)^{2} \left(1 + \frac{\gamma_{j}^{2}}{k_{z_{j-1}}^{2}}\right) \\ &+ \frac{1}{2} \left(\cos^{2} \widetilde{\varphi}_{j+1} - \frac{k_{z_{j+1}}^{2}}{\gamma_{j}^{2}} \sin^{2} \widetilde{\varphi}_{j+1}\right) \left(1 - \frac{\gamma_{j}^{2}}{k_{z_{j-1}}^{2}}\right) \\ &+ \frac{\Gamma_{j}^{2}}{4} \left(\cos \widetilde{\varphi}_{j+1} + \frac{k_{z_{j+1}}}{\gamma_{j}} \sin \widetilde{\varphi}_{j+1}\right)^{2} \left(1 + \frac{\gamma_{j}^{2}}{k_{z_{j-1}}^{2}}\right), \end{split}$$

$$(41)$$

where $\Gamma_j = \exp(-\gamma_j s_j) \ll 1$ and $\widetilde{\varphi}_{j+1} = \varphi_{j+1} - \Delta_{j+1}$.

Thus, to calculate $l_{\text{loc}_{\text{ref}}}^{-1}$, one has to perform the averaging in Eq. (36) with A_{j-1}/A_{j+1} substituted from Eq. (41). In accordance with Eq. (11) in the short-wave limit we first average over uniformly distributed random phases $\tilde{\varphi}_{j+1}$, which in the first approximation in the small parameter $\Gamma_j \ll 1$ after rather cumbersome calculations yields

$$\frac{1}{2\pi} \int_0^{2\pi} \ln \frac{A_{j+1}}{A_{j-1}} d\widetilde{\varphi} = \ln \Gamma_j [1 + O(\Gamma_j^2)] \approx \gamma_j s_j. \tag{42}$$

Equation (42) shows that change of the amplitude caused by the tunneling through a reflected layer is determined mainly by the attenuation rate γ inside the layer and is practically independent on the parameters of the adjacent transparent layers.

Finally, taking into account Eqs. (11), (36), (39), and (42) for the contribution of the reflecting layers to the inverse localization length we obtain

$$I_{\text{loc}_{\text{ref}}}^{-1} = (2s)^{-1} \int ds' F_s(s') \int_{n' < n_c} dn' F_n(n') s' \gamma(n')$$

$$= \frac{k_0}{2} \int_{n' < n_c} dn' F_n(n') \sqrt{n_c^2 - n'^2}.$$
(43)

Evidently, this contribution does not depend on the wave polarization. Therefore, the resulting inverse localization length for *S*-polarized or *P*-polarized waves can be obtained from Eq. (35) with $I_{\text{loc}_{tr}}^{-1}$ substituted by Eqs. (23) or (24), respectively.

When $N_{\rm ref}/N_{\rm tr} \ll 1$ (in the opposite limit the effect of transparent layers is negligible and the exponential decay of the transmission coefficient has nothing to do with localization), Eq. (35) with account made for Eqs. (37) and (43) transforms to

$$l_{\text{loc}}^{-1} \approx l_{\text{loc}_{\text{tr}}}^{-1} + \delta, \quad \delta = \frac{2N_{\text{ref}}}{N} l_{\text{loc}_{\text{ref}}}^{-1} = k_0 \int_{n' < n_c} F_n(n') dn'$$

$$\times \int_{n'' < n_c} F_n(n'') \sqrt{n_c^2 - n''^2} dn''.$$
(44)

It is easy to see that the ratio $\delta/l_{\rm loc_{tr}} \propto l_{\rm loc_{tr}}/l_{\rm loc_{tr}}$ is proportional to $k_0 s \gg 1$, which means that the influence of the reflecting layers can be significant even when their number is small.

To demonstrate characteristic physical features of the localization in the presence of reflecting layers we consider a medium consisted of statistically independent random layers with rectangle distribution function of the refractive index F_n :

$$F_n(\zeta) = \begin{bmatrix} (n_{\text{max}} - n_{\text{min}})^{-1}, & n_{\text{min}} < \zeta < n_{\text{max}}, \\ 0, & \zeta < n_{\text{min}} & \text{or } \zeta > n_{\text{max}}. \end{bmatrix}$$
(45)

Reflecting layers exist if $n_{\min} < n_c$. When $1 - n_{\min}/n_c < 1$, the relative numbers of reflecting and transparent slabs are

$$\frac{N_{\text{ref}}}{N} = \frac{n_c - n_{\text{min}}}{n_{\text{max}} - n_{\text{min}}} \ll 1, \quad \frac{N_{\text{tr}}}{N} = \frac{n_{\text{max}} - n_c}{n_{\text{max}} - n_{\text{min}}} \approx 1. \quad (46)$$

In this case after substitution of Eq. (45) into Eq. (44) one obtains

$$\delta = \frac{k_0(n_c - n_{\min})}{2(n_{\max} - n_{\min})^2} \int_{n_{\min}}^{n_c} \sqrt{n_c^2 - n'^2} dn'$$

$$= \frac{k_0 n_c^2 (n_c - n_{\min})}{2(n_{\max} - n_{\min})^2} \arcsin\left(\frac{n'}{n_c}\right) \Big|_{n_{\min}}^{n_c}$$

$$\approx \frac{k_0 n_c^3}{\sqrt{2}(n_{\max} - n_{\min})^2} \left(1 - \frac{n_{\min}}{n_c}\right)^{3/2}.$$
(47)

The contribution to the inverse localization length from transparent layers, $I_{\rm loc_{tr}}^{-1}$, is given by Eqs. (23) and (24). If, for example, the values of $n_{\rm max}$ and $n_{\rm max}-n_{\rm min}$ are of the order of 1, $n_{\rm max} \sim n_{\rm max}-n_{\rm min} \sim$ 1, it is easy to show that

$$l_{\rm loc_{tr}}^{-1} \sim s^{-1}$$
. (48)

From comparison Eq. (48) with the Eq. (47) the following conditions can be obtained for the contribution of the reflecting layers to be of the same order as that of the transparent ones:

$$n_{\min} \sim n_c - \frac{1}{n_c (k_0 s)^{2/3}},$$
 (49)

when the angle of propagation, $\vartheta_0 \sim n_c$, is fixed, and

$$\vartheta_0 \sim \frac{n_{\min}}{2} + \sqrt{\frac{n_{\min}^2}{4} + \frac{1}{(k_0 s)^{2/3}}},$$
 (50)

when n_{\min} is fixed. Note that the angle ϑ_0 in Eq. (50) is always larger than $(k_0s)^{-1/3}$. Hence, when $\vartheta_0 < (k_0s)^{-1/3} \le 1$, the influence of the reflecting layers is small independently on n_{\min} .

Figure 1 shows the typical dependences $l_{\log_{S,P}}^{-1}(\vartheta_0)$ calculated numerically for the rectangle distribution function, Eq. (45).

V. CONCLUSION

Transmission of a plane monochromatic transverse wave obliquely incident on a randomly layered medium has been studied, and the inverse localization length determined as $l_{\text{loc}}^{-1} = -\langle \ln T/2L \rangle$ has been calculated in the high-frequency (strong disorder in terms of Ref. 6) limit. The method of

calculation takes advantage of the fact that in the localization regime the energy flux at typical realizations is zero (with exponential accuracy), and therefore the field inside each layer can be considered as a standing wave. The assumption is also used that the phases at the interfaces of layers are uniformly distributed in the interval $[0,2\pi)$. The approach is rather general and simplifies calculations significantly as compared to the conventional transfer matrix approach. With this method we have shown that the inverse localization length of S waves increases with the angle of propagation and is always larger than the localization length of P waves, which, in contrast, goes down as the angle of incidence grows and reaches a minimum at some angle (stochastic analog of the Brewster effect). The effect is most pronounced in a medium consisting of alternating layers of two dielectrics with random widths. In this case $l_{loc} \rightarrow \infty$ at the Brewster angle; i.e., the localization is absent for P waves. If in a random sample there are layers with the refractive index small enough, $n < \sin \vartheta_0$, strong internal reflection from these layers can reduce significantly the total transmission. This reduction is described by an additive term in the inverse localization length, which depends on the number of layers that are reflecting at the given angle of incidence and on the statistics of their parameters (width and dielectric constants). The conditions for this term to be comparable with the contribution from transparent layers have been discussed. The revealed dependence of the localization length on the angle of propagation could play a vital part in formation of the field of a source radiating in different directions and enhance significantly the waveguiding effect in randomly layered media. ¹²

ACKNOWLEDGMENTS

The work was partially supported by INTAS (Grant No. 03-55-1921), Ukrainian President Grant for Young Scientists GP/F8/51, and Israeli Science Foundation (Grant No. 328/02).

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¹I. M. Lifshits, S. A. Gredeskul, and L. A. Pastur, *Introduction to the Theory of Disordered Systems* (Wiley, New York, 1988).

²P. Sheng, *Introduction to Wave Scattering, Localization, and Mesoscopic Phenomena* (Academic, Boston, 1995).

³L. D. Landau and E. M. Lifshitz, *Electrodynamics of Continuous Media* (Pergamon, New York, 1984).

⁴V. Kliatskin, Stochastic Equations and Waves in Randomly Inhomogeneous Media (Nauka, Moscow, 1980).

⁵K. Yu. Bliokh, Waves Random Media **13**, 1 (2003).

⁶V. Baluni and J. Willemsen, Phys. Rev. A **31**, 3358 (1985).

⁷A. R. McGurn, K. T. Christensen, F. M. Muller, and A. A. Maradudin, Phys. Rev. B **47**, 13120 (1993).

⁸ V. D. Freilikher, B. A. Liansky, I. Yurkevich, A. A. Maradudin, and A. R. McGurn, Phys. Rev. E 51, 6301 (1995).

⁹M. V. Berry and S. Klein, Eur. J. Phys. **18**, 222 (1997).

¹⁰ K. Yu. Bliokh, Zh. Eksp. Teor. Fiz. **121**, 14 (2002) [JETP **94**, 8 (2002)].

¹¹ K. Yu. Bliokh and O. V. Usatenko, Int. J. Mod. Phys. B **16**, 4865 (2002).

¹²V. D. Freilikher and S. A. Gredeskul, Prog. Opt. **30**, 137 (1992).